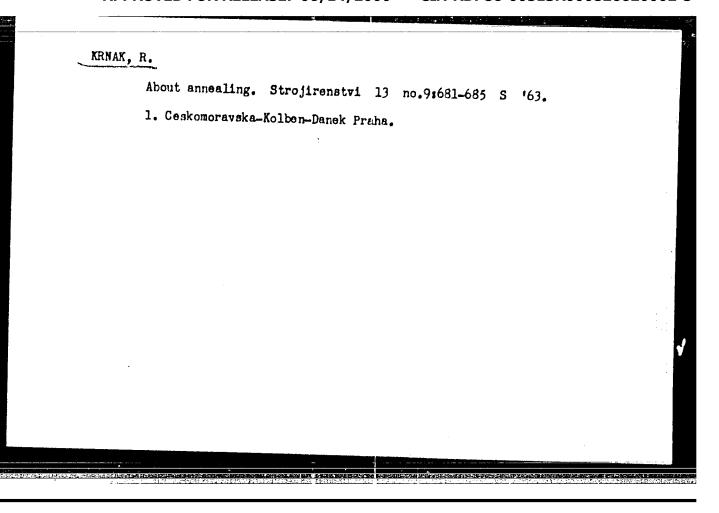
# KRNAK, Rudolf

"Course of gas welding in questions and answers" by Boleslaw Szupp, Leon Mistur. Reviewed by Rudolf Krnak. Stroj vyr 11 no.8: 422 Ag \*63,



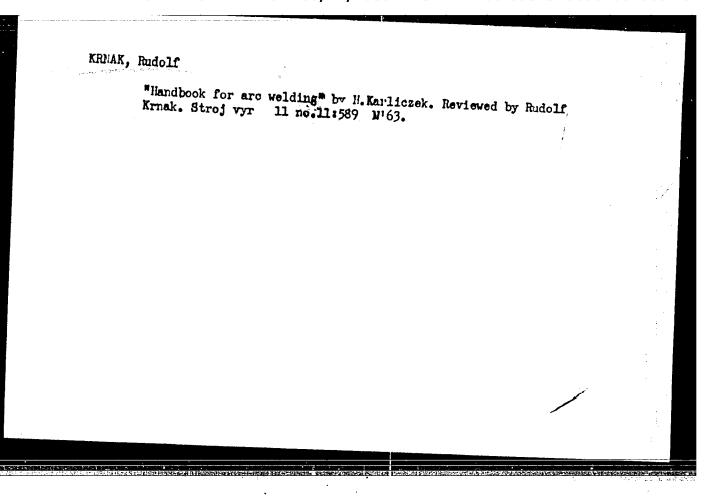
### KRNAK, R.

"Welding and flame cutting" by D.L.Glizmanenko, G.B.Jevsejev [Yevseyev, G.B.]. Reviewed by R.Krnak. Strojirenstvi 13 no.6:477 Je '63.

### KRNAK, Rudolf

"Control of the quality of welds and welded structures" by I.N. Bondin. Reviewed by Rudolf Krnak. Stroj vyr 11 no.10:533 0 163.

# KRNAK, Rudolf "Technology of electric fusion welding" edited by B.E.Paton. Reviewed by Rudolf Krnak. Stroj vyr 11 no.92475 S 163.



KRNAK, Rudolf; VRANA, Boleslav, nositel Radu prace

On the quality of welding. Stroj vyr 12 no.1:34-35 Ja'64.

# Technological weldment processes. Zvarnie 13 no.2:39-44 F '64. 1. Ceskomoravska-Danek Praha.

KRNAK, Rudolf

Importance of mechanization devices in welding. Zvaranie 14 no.1: 16-19 Ja 165.

1. Ceskomoravska-Kolben-Danek National Enterprise, Prague.

KRNAN, Frantisek

Fyzika pre 1. roc. priem. skol. (Physics for the 1st grade of industrial schools. a textbook. 3d ed. illus., notes) Authors: Frantisek Krman and Ivan Nater. Bratislava, SPN, 1957. 254 p.

Bibliograficky katalog, CSR, Slovenske Khihy, Vol. VIII. 1957. No. 9. p. 275.

38907-66 IJP(c) ACC NR: AP6029572 SOURCE CODE: CZ/0045/65/000/002/0097/0115 AUTHOR: Krnyan, Frantishek--Krnan, F. (Bratislava) B ORG: Department of Mathematics and Descriptive Geometry, Engineering Faculty, Slovak Institute of Technology, Bratislava (Katedra matematiky a deskriptivnej geometrie, Strojnicka fakulta, Slovenska vysoka skola technicka) TITLE: Study of the structure of the semigroup of square matrices of the order n over a given field SOURCE: Matematicko-fyzikalny casopis, no. 2, 1965, 97-115 TOPIC TAGS: group theory, mathematic matrix, field theory ABSTRACT: The structure of the semigroup S(n) of the square matrices of the order n over a given field is approached by the method of decomposition of singular matrices of the rank  $r \neq 0$  into the produce A = LM of two matrices of the types n/r and r/nof the maximal rank r. Orig. art. has: 13 formulas. [Based on author's Eng. abst.] SUB CODE: 12 / SUBM DATE: 09Jul63 / ORIG REF: 001 / SOV REF: 005 OTH REF: 001 Card 1/1

# KRNETA, Branko

Opening of the federal centers for education of instructors in construction and mining industries and in commerce. Produktivnost 3 no.11:

KRNIC, Marko, inz. (Osijek)

Rentability of the processing of glycerin lye depending on its concentration. Kem ind 12 no.4:231-233 Ap \*63.

KRNIC, Marko, inz.

Quantum working conditions in kernel soap washing. Kem in 12 no.10:755-758 0.63.

1. "Saponia", Osijek, Istrazivacki institut.

# KRNICH, Luka [Krmic, Luka] (Zegrob)

A note on computing algebra of logic bases constructed with the aid of functions of one or two variables. Clasmat fiz Hrv 18 no.1/2:13-16 163.

2715

5/081/62/000/021/019/069 B156/B101

AUTHORS:

Kukolja, S., Polak, Lj., Krnjević, H., Videk, M.

TITLE:

Substances acting on the central nervous system. IV, Derivatives of 2-ethyl-2-phenyl butyramide

PERIODICAL: Referativnyy zhurnal. Khimiya, no. 21, 1962, 157, abstract 21Zh125 (Croat. chem. acta, v. 33, no. 3, 1961, 121 - 126 (Engi); summary in Serb.-Croat;))

TEXT: Research to find substances acting on the central nervous system has involved the synthesis of a number of derivatives of 6H5C(C2H5)2COOH) (acid I):  $c_6H_5c(c_2H_5)_2$ conhr (II),  $c_6H_5c(c_2H_5)_2$ conhcor (III) and  $4-hc_6H_4c(c_2H_5)$ cor (IV). To 0.1 mole I in 200 ml absolute C6H6 40 ml SOCl are added; the whole is boiled for 2 hrs, and the volatiles distilles off; without any further purification, the acid chloride is dissolved in 50 ml  ${\rm C_{6}H_{6}}$  or  ${\rm HCON(CH_3)_2}$ , 0.05 mole of anhydrous  ${\rm Na_2CO_3}$  and 0.1 mole of the appropriate amide added, and the mixture heated for 2 hrs at ~ 100°C and left for Card 1/5

Substances acting on the central ...

S/081/62/000/021/019/069 B156/B101

from the combined filtrates [R, the gross formula, the yield in %, and the melting point in °C (from alcohol) are given):  $C_2H_5$ ,  $C_{14}H_{21}N0$ , 90, 103 - 104;  $CH_2CH_2N(C_2H_5)_2$ ,  $C_{18}H_{51}CIN_2O$  (hydrochloride), 60, 164 - 165 (from alcohol ether);  $CH_2CH_2OH$ ,  $C_{14}H_{21}NO_2$ , 81, 66 - 67.5 (from benzene + petroleum ether);  $-CH_2CH_2-$ ,  $C_{26}H_{56}N_2O_2$ , 80, 107 - 109 (from benzene + petroleum ether);  $C_6H_5$ ,  $C_{18}H_{21}NO$ , 89, 85 - 86.5;  $CH_2C_6H_5$ ,  $C_{19}H_{25}NO$ , 85, 120 - 122; 5-propyl mercapto thiadiazoke-1,3,4-y1-2,  $C_{17}H_{23}N_3OS_2$ , 78, 99 - 91; 5-isopropyl mercapto thiadiazoke-1,3,4-y1-2,  $C_{17}H_{23}N_3OS_2$ , 61, 91 - 93; 2-phenyl-pyrazolyl-5,  $C_{21}H_{23}N_3O$ , 70, 126 - 128. 0.02 mole of  $C_6H_5$ ,  $C_{C_2}H_5$ )<sub>2</sub> $CONH_2$  (V) and 0.02 mole NaNH<sub>2</sub> are boiled in 15 ml of anhydroun  $C_6H_6$  for 2 hra; after cooling, 0.025 mole of RCOCl are added and the mixture is boiled for 2 hrs; after 12 hra, at 20°C, 10 ml of water are added, and III is separated from the organic layer [(R, the gross formula, Card 2/5]

Substances acting on the central ...

8/081/62/000/021/019/069 B156/B101

the percentage yield, and the melting point in OC (from alcohol) are given]: CH<sub>3</sub>, C<sub>14</sub>H<sub>19</sub>NO<sub>2</sub>, 18, 89 - 92; C<sub>2</sub>H<sub>5</sub>, C<sub>15</sub>H<sub>21</sub>NO<sub>2</sub>, 15, 100 - 102;  $^{\text{C}}_{6}^{\text{H}}_{5}$ ,  $^{\text{C}}_{19}^{\text{H}}_{21}^{\text{NO}}_{2}$ , 12, 123 - 125;  $^{\text{CHBrCH}(\text{CH}_{3})}_{2}$ ,  $^{\text{C}}_{17}^{\text{H}}_{24}^{\text{BrNO}}_{2}$ , 10, 114 - 116. During 20 min, 4 ml of fuming HNO3 are added under cooling to 10 g I in 40 ml of concentrated  $H_2SO_4$ , and the mixture is held at 0 - 10°C for 30 min; it is poured onto ice, and 46 % of IV (R = NO<sub>2</sub>, R' = OH) (IVa),  $C_{12}H_{15}NO_4$ , m.p. 144 - 1460C (from benzene) are separated by recrystallization. 2.4 g IVa and 0.5 g anhydrous Na<sub>2</sub>CO<sub>3</sub> in 15 ml water are hydrogenated over 0.05 g of Pd/C at ~ 20°C and 760 mm; the filtrate is neutralized with HCl, and 70 % of IV (R = NH<sub>2</sub>, R' = OH) (IVb), C<sub>12</sub>H<sub>17</sub>NO<sub>2</sub>, m.p. 166 - 1670C (from alcohol), are separated. 1 g IVb in 10 ml (CH3CO)2O is boiled for 2 hrs, the excess of anhydride evaporated, and the residue dissolved in 10 % Na<sub>2</sub>CO<sub>3</sub>; acidifying the alkaline solution provides 41.5% of IV (R = CH<sub>3</sub>CONH, R' = OH) (IVo), C<sub>14</sub>H<sub>19</sub>NO<sub>3</sub>, m.p. 197 - 198°C (from aqueous

Card 3/5

S/081/62/000/021/019/069 Substances acting on the central ... alcohol). Another substance produced from IVa is IV (R = N(CH<sub>3</sub>)<sub>2</sub>, R' = OH) (IVd), CH<sub>14</sub>N<sub>21</sub>NO<sub>2</sub>, yield 83 %, m.p. 145 - 146°C (from dilute alcohol). 0.5 g IVd are methylated with CH2N2 produced from 1 g nitroso-methyl carbamide, and the methyl ester of IVd  $[R = N(CH_3)_2, R' = OCH_3], C_{15}^{H_{23}NO_2}$ is obtained; yield 90 %, m.p. 79 - 80°C. The methyl ester (R = CH3CONH,  $R' = OCH_3$ ),  $C_{15}H_{21}NO_3$ , (yield 90 %, m.p. 143 - 144°C) is synthesized in an analogous manner from 0.6 g of IVc. 10 g IV ( R = H,  $R' = NH_2$ ) (IVe) are cooled with ice and added to 50 ml of concentrated H2SO4, and during 20 min at 0 - 1000 4 ml of fuming HNO3 are added drop by drop; the mixture is held in ice for 30 min, and poured out onto ice; the resultant product is 54 % of IV (R =  $NO_2$ , R' =  $NH_2$ ) (IVf),  $C_{12}H_{16}N_2O_3$ , m.p. 127 - 128°C. To 1 g IVa in 10 ml  $C_6H_6$  2 ml of  $SOCl_2$  are added; the mixture is boiled for ? hrs, the volatile substances evaporated, the residue dissolved in 10 ml C6H6 and saturated with NH3 gas; the product is 40 % of IVf. By nitrating

Substances acting on the central...

S/081/62/000/021/019/069 B156/B101

10 g C<sub>6</sub>H<sub>5</sub>C(C<sub>2</sub>H<sub>5</sub>)<sub>2</sub>CN (VII) in a manner analogous with the production of IVa, 47.5 % of 4-No<sub>2</sub>C<sub>6</sub>H<sub>4</sub>C(C<sub>2</sub>H<sub>5</sub>)<sub>2</sub>CN (VIII), C<sub>12</sub>H<sub>14</sub>N<sub>2</sub>O<sub>2</sub>, m.p. 81 - 830C (from benzene) are synthesized. 3 g VIII in 10 ml 96 % H<sub>2</sub>SO<sub>4</sub> are heated for 8 hrs at 700C and poured onto ice; 67 % IVf are extracted with C<sub>6</sub>H<sub>6</sub>. IV is correspondingly produced in a manner analogous with that described above for the synthesis of IVd and IVe (R, R', the gross formula, the initial substance, the percentage yield, and the melting point in °C, are given): N(CH<sub>3</sub>)<sub>2</sub>, NH<sub>2</sub>, C<sub>14</sub>H<sub>22</sub>N<sub>2</sub>O, IVf, 79, 119 - 120; NH<sub>2</sub>, NH<sub>2</sub>, C<sub>12</sub>H<sub>18</sub>N<sub>2</sub>O, IVf, 53, 142 - 143. 85 g VII, 250 ml concentrated H<sub>2</sub>SO<sub>4</sub>, and 25 ml water are heated at 100°C for four hrs, and then after cooling poured onto ice, C<sub>6</sub>H<sub>6</sub> being used for extracting 81 % of nonpurified IVe, m.p. 49 - 51°C. 77 g of nonpurified IVe are treated by the method described earlier (see N. Sperber et al, J. Amer. Chem. Soc., v. 70, 1948, 3091), with C<sub>4</sub>H<sub>9</sub>ONO in III, see RZhKhim, 1962, 8Zh134. [Abstracter's note: Complete translation.]

CZECHOSLOVAKIA 12 Aug 66

### KRNO, D.M.

State Planning and Statistica Office. Since June 1949 Ambassador to Austria; returned to Czechoslovakia on his own request. Afterwards working and the Komensky University, at first as head of the Department of International Law and Covernment (at the Faculty of Law) and since 1954 as head of the Department of Journalism at the Faculty of Philosophy of Komensky University. Author of numerous books. Celebrated his 65th borthday on 12 August (Photo of Krno is given)

Praca, Bratislava, 12 Aug 66, p 4. (two of two)

(1)

## CIA-RDP86-00513R000826620002-5"

Appiloations - er wice Gland Bosting meterials : Righton., Ro. 16 1909, No. 57746

AUGHOR : Kroach, M. lagr.

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i rene 1 The Silicates Inematry in Hungary

CAIG. PUB. : Empitodanyes, 10. No 12, 417-419 (1998)

ABSTRACT : No abstract.

CARD: 1/1 Concrete.

KRCBA, F.

"Preventing the Breaking of the Cylinder Heads of Skoda 706 RO Motors." p. 86 "Possible Effects of the Incorrect Temperature of Cooling Water." p. 87 (Svet Motoru, Vol. 7, no. 139, Feb. 1953, Praha)

So: Monthly List of East European Vol. 3, No. 3

Resetten Accessions,/Library of Congress, March

1954 1953, Uncl.

ACC NR. AP6030800 SOURCE CODE: UR/0346/66/000/009/0087/0089 AUTHOR: Kolomakin, G. A. (Doctor of veterinary sciences); Krobchenko, M. I. (Director); Bel'chenko, G. A. (Veterinary doctor) ORG: Kazakh Republic Veterinary Laboratory (Kazakhskaya respublikanskaya veterinar-TITLE: Precipitation reaction in agar gel in rabies SOURCE: Veterinariya, no. 9, 1966, 87-89 TOPIC TAGS: animal disease, rabies, disease diagnosis, diagnostic method, precipitation reaction , gel, chemical precipitation ABSTRACT: For three years the authors have used a reaction of precipitation in agar gel for rabies diagnosis which was developed in the Department of Epizootology of the Alma-Ata Zootechnical and Veterinary Institute. Standard histological methods were. also used in rabies detection. This reaction did not give positive results for 96 animals dying from various causes or for 83 animals dying from other infectious diseases. However, positive precipitation-reaction results for 257 agricultural and wild animals were supported by positive diagnosis of rabies by other methods. The authors were most interested in the Card 1/2 UDC: 619:616.988.21-077.34

### ACC NRI AP6030800

demonstrated high specificity of the method, particularly for cases in which other diagnostic methods, especially examination for Babes-Negri bodies, do not yield positive results. . However, for a number of reasons (quality of gamma-globulin used in the reaction, precipitinogenic properties of the infective strain, and laboratory conditions), PR does not always yield positive results in confirmed rabies cases. The diagnostic accuracy of the PR is increased when separate suspensions are prepared from various parts of the brain, rather than one general suspension. No relationship was noticed between the degree of precipitinogenicity of the brains of rabid animals and the time of death of mice infected with their brain tissue. It is also suggested that better results may be obtained when ten, rather than six, infant mice are used for bioassay, as bioassay using six older mice, followed by PR of their brain tissue did not always confirm rabies diagnosis. PR using a good-quality gamma globulin showed results in as little as 24 hr. The method also shows potential for use with unfresh or frozen material. Negative PR does not, however, definitely indicate the absence of rabies virus. This method will be included in diagnostic studies of rabies. [WA-50; CBE No. 12]

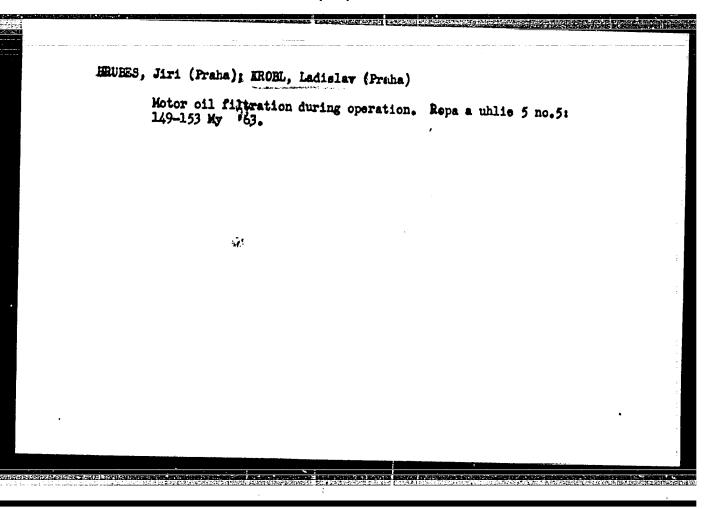
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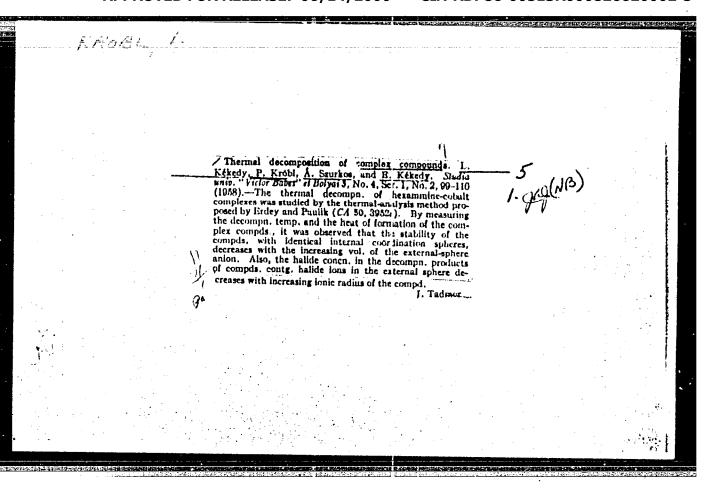
Card 2/2

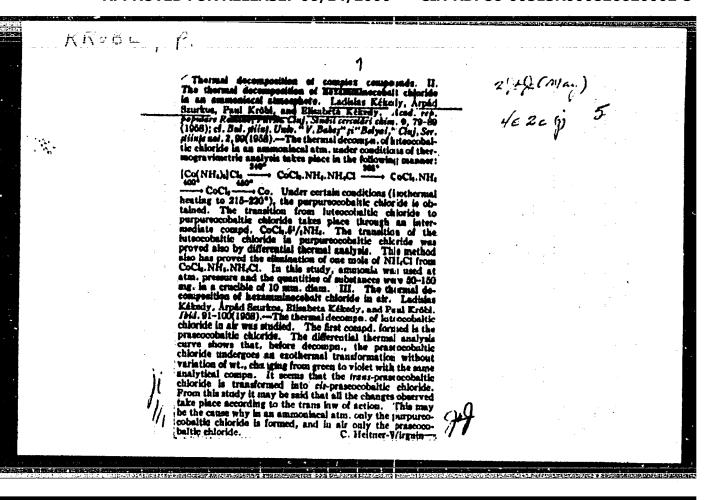
RYLSKI, Leszek; PAC-POMARNACKA, Elzbieta; STRU?CZEWSKA, Elzbieta; KROBJILOWSKA, Magdalena; ZANDER, Krystyna

Synthesis of some amino derivatives of 2-phenethylamine. Acta Pol. pharm. 22 no.3:197-201 165.

1. Z Zakladu Technologii Chemicznej Srodkow Leczniczych Akademii Medycznej w Gdansku (Kierownik: doc. dr. L. Rylski).







COUNTRY CAT 90 ORY	: RUMAKIA Complex Compounds
BS. JOUR.	: RZKhim., No. 1 1960, No.693
UTHOR	: Kekedy, L.; Szurkos, A.; Kekedy, E.; Krobl, P.
nst. HTLE	: Rumanian AS, Gluj Affiliate : On Thermic Decomposition of Complex Compounds. III. Thermic Decomposition of Hexammino-Cobalt Chloride in Air
ORIG. PUB.	: Studii si cercetari chim. Acad. RPR Fil. Cluj, 1958, 9, No 1-4, 91-100
ABSTRACT	: The thermic decomposition of [Co(IH3)6]Cl3 in air in the temperature interval of 0-700° was investigated. It was established that [Co(IH3)6]Cl3 transforms upon decomposition, splitting off two molecules of IH3, into trans-[Co(IH3)4Cl2]Cl which, prior to further decomposition, transforms into a violet salt of the same composition, apparently into cis-[Co-
CARD:	1/2
	C-10

COUNTRY C CATEOORY : RZKhim., No. 1 1960, No. 693 ABS. JOUR. AUTHOR INST. TITLE ORIG. PUB. : : (NH<sub>3</sub>) Cl<sub>2</sub>Cl. These processes are explained from the viewpoint of the effect of trans-influence if it is assumed that in the com-pounds of Co (+3) the trans-influence of Cl ABSTRACT cont'd is greater than that of MI3. Report II, see RZhKnim., No 21, 1959. No 74490.-- Yu. Knaritonov CARD: 2/2

FELSZECHY, E., STOICSVICI, E.; MAGY, L.; MROBL, P., LITEROT, 1.
ILIES, M.

Contributions to the study on the colloidal clays in Rumania. Pt. 6. Studia Univ B-B S. Chem 8 no. 2,95-105 163.

KROBL, Paul; WACNER, Iosif.

Chemical and physical study of coal in Rumania. Studia Univ B-B S Chem 8 no.12473-480 163

1. "Babes-Bolyai" University, Cluj.

мене за высоком станиционня принада на бита принада на принада на бита на принада на принада на принада на при

MISINGER, I.; KROBOVA, I.; SKODA, V.; TRNKA, V.

Contribution to the treatment of climacteric and post-castration osteoporosis and osseous metastases of gynecological cancer. Cesk. gynek. 30 no.8:566-568 0 165.

1. II. gyn.-por. klin. fakulty vseobecneho lekarstvi Karlovy University v Praze (prednosta prof. dr. J. Lukas, DrSc.). Submitted December 29, 1964.

KRCC, L.

The influence of a load on the motion of a servomechanism and its reduction.

P. COl. (SLABOPROUDY OBZOR.) (Praha, Czechoslovakia) Vol. 18, No. 10, Oct. 1957

SO: Monthly Index of East European Accession (EEAI) LC. Vol. 7, No. 5, 1958

KROC, Ladislav, inz., CSc.

Electromagnetic systems of electromechanical transducers. Automatizace 6 no.6:133-136 Je '63.

1. Vpjenska akademie Antonina Zspotockeho.

L 38758-66 EWT(d)/FWT(m)/FWP(k)/FWP(h)/FWP(v)/FWP(t)/FWP(1)/FTI JP(c) JD/ACC NR: AP6029568 HW/PC SOURCE CODE: CZ/0057/65/000/009/0381/0385	•
AUTHOR: Krocek, Frantisek	
ORG: NHKG, Ostrava	
TITIE: Use of a computer in rolling calculations 10	
SOURCE: Hutnik, no. 9, 1965, 381-385	
TOPIC TAGS: metal rolling, computer, computer program, industrial development  ABSTRACT: Practical examples of calculation of rolling pressures are discussed.  The use of these calculations in the design of new plants is described. The method of using computer programs for optimizing profiles of rolled products is described.  Oxig. art. has: 2 figures and 3 tables. [JPRS]	
SUB CODE: 13, 09, 05 / SUBM DATE: none / ORIG REF: 004	
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Card 1/1	
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one de la company de la compan	0004740040

POPOVA, L.A.; KROCHAGIN, V.B.

Determination of nystatin during the process of fermentation.

Antibiotiki 5 no.1:58-62 Ja-F 160. (MIRA 13:7)

1. Vsesoyuznyy nauchno-issledovatel skiy institut antibiotikov. (MYCOSTATIN)

#### "APPROVED FOR RELEASE: 06/14/2000 CIA-RDP86-00513R000826620002-5

AUTHOR:

Krochakevich, V. D., Engineer (Riga)

TITLE:

Charging a Capacitor From an A C Source Through a destifier (Zaryad kodensatora o a istochnika per mennent teka cherez

vypryamitel')

PERIODICAL:

Elektrichestvo. 1958, Br 3, pp 69-70 (6332)

ABSTRACT:

The pulsations of the rectified voltage have a great influence on the charging of capacitors with a great capacity, if the charging period essentially exceeds the period of the supply current. This, because a charging occurs only at such moments. where the applied pulsating voltage nexceeds the voltage at the capacitor ug. An increase of the number of phase in rectifying leads to an acceleration of charging. It is assumed, that the parameters of the circuit have the same influence on the course taken by the entire process as is the case at the application of a constant voltage. Differential equations are set up for the determination of the equivalent circuit parameters, which describe the processes occuring in the circuit. For this purpose, the usual assumptions of rectifier theory are made (Ref. 1) and it is furthermore assumed, that the switching on

Card 1/2

CIA-RDP86-00513R000826620002-5"

APPROVED FOR RELEASE: 06/14/2000

Charging a Capacitor From an A.C. Source Through a Restifier 105.58-3-18/31

is performed within the sircuit of the rectified current. The formulae (1) and (2) for the equivalent resistance is or the equivalent inductivity  $L_2$  are sequed. From (1) it is seen, that requivalent is dependent not only upon the resistances, but also on the impedances of the accordinate as well as on the frequency. This dependence is also proved experimentally. From the rules governing the aperiodic regime and from (1) and (2) follows, that an increase of the secondary voltage of the stepping-up transformer can benefit a slower down of charging. There are 3 figures and 1 Soviet reference.

SUBMITTED:

November 19, 1957

AVAILABLE:

Library of Congress

Card 2/2

8 (3)

AUTHOR:

Krochakevich, V. D., Candidate of

SOV/105-59-12-13/23

THE REPORT OF THE PARTY OF THE

Technical Sciences (Riga)

TITLE:

Duration of the Transition Processes in Circuits With 3-Phase

Bridge Rectifiers

PERIODICAL:

Elektrichestvo, 1959, Nr 12, pp 61-63 (USSR)

ABSTRACT:

To improve the protective connection and the automatic controls of a.c. circuits a d.c.-equipment is used. The latter is fed via semiconductor rectifiers (with different wirings). The singlephase rectifiers have the disadvantages described in the article, which do not occur in 3-phase bridge-rectifier wiring. In the latter case the relation of the amplitude of the variable voltage component to the average (mean) value is 5.7% instead of the 66% in the single-phase bridge-rectifier wiring. Due to this, the initial phase has no influence on the current increase rate. In automation networks impulse generators are also used. These are fed via reatifiers from capacity power storages. The operation cycle of these generators is mainly determined by the charging time of the condensor, which is considerably shorter in 3-phase bridge rectifier wiring than in single-phase wiring. The author shows that by selection of the

Card 1/2

Duration of the Transition Processes in Circuits With 3-Phase Bridge Rectifiers

sov/105-59-12-13/23

parameter of the rectifier equipment and by connecting condensemate the a.c. circuit (before the rectifiers), when needed, the duration of the transition processes in the circuits with 3-phase bridge rectifier can be varied within wide limits. Besides, the quick operation of the d.c.-fed apparatus is considerably increased. There are 4 figures and 3 Soviet references.

SUBLITIED:

March 24, 1959

Card 2/2

SOV/137-58-10-20698

Translation from: Referativnyy zhurnal, Metallurgiya, 1958, Nr 10, p 52 (USSR)

AUTHOR: Katsenelenbogen, P.D., Krochevskiy, V.A., Smirnov, M.N.

TITLE: Complex Utilization of Kola Nepheline Concentrate (Kompleks-noye ispol'zovaniye Kol'skogo nefelinovogo kontsentrata)

PERIODICAL: V sb.: Legkiye metally. Nr 4. Leningrad, 1957, pp 37-43

ABSTRACT: Note is taken of a number of features of production engineering and equipment found in the course of investigations of and development of a procedure at the Volkhov Aluminum Plant. Emphasis is given to the need for preparing the charge on the basis of extraction of aluminate caustics and Ca silicate. Permissible maxima for impurities in the limestone and the nepheline concentrate are established. It is recommended that sintering be done to a dense condition such as clinker. It is desirable to combine grinding and leaching of the sinter at 68-70°C. The concentration of aluminate solutions is 80-90 g Al<sub>2</sub>O<sub>3</sub>/ liter. The grain size of the ground clinker is from +1 to -0.088 mm. The time required for silicon removal is 2-3 hours at 160-170°. It is desirable that carbonization be in 2 Card 1/2 stages, the residual Al<sub>2</sub>O<sub>3</sub> contents being 4 g/liter in the first

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SOV/137-58-10-20698

Complex Utilization of Kola Nepheline Concentrate

stage and 0.1-0.2 g/liter in the second. Equipment is chosen for each stage in the process, and a procedure for the employment thereof is developed. A high-output thickening filter, rendering contact between solids and fluids impossible (to avoid secondary reactions) is designed and perfected.

L.P.

1. Hephelited ores--Processing 2. Nephelite ores--Applications

**Card 2/2** 

L 46833-66 EWT(1)/EWT(m)/EWP(j) IJP(c) WW/GG/RM
ACC NR. AR6013639 SOURCE CODE: IR

SOURCE CODE: UR/0058/65/000/010/D054/D054

AUTHOR: Krochik, A. S.

45

REF SOURCE: Visnyk L'vivsk'. un-tu. Ser. fiz. L'viv, 1964, 25-29

B

TITLE: Study of the shapes of self-absorption bands in a phenanthrene

rvstal

SOURCE: Ref. zh. Fizika, Abs. 10D381

TOPIC TAGS: phenanthrene, phenanthrene single crystal, exciton, phonon interaction, absorption band

TRANSLATION: The absorption of light in a phenanthrene single crystal was investigated in a broad temperature range (4.2-290°K). True shapes of absorption bands were obtained. The temperature dependence of the half-width of the 0-0 transition band, its asymmetry, peak displacement and the shape of the absorption band are studied. The characteristic temperature is determined as 40-50°K. Therefore, changes in the degree of asymmetry and even more so the change in its sign when the temperature is lowered from 20 to 4.2°K, cannot be associated with changes in the exciton-phonon interaction. These changes can be associated with the effect of spatial dispersion and the complex structure of the exciton zone. Apparently this offers a reasonable explanation for the complex shape of the 0-0 transition absorption band at low temperatures.

SUB CODE: 20/

SUBH-DATE - DOME

Card 1/1 blg

UDC: 535.33; 535.34; 5480:535

BASOW, N. G. [Basov, N. G.]; KROCHIN, O. H. [Krokhin, O. N.]; POPOW, J. M. [Popov, Yu. M.]

Preparation of states with negative temperature at p-n transitions of degenerated semiconductors. Acta phys Hung 14 no.2 3: 241-243 '62.

1. P. N. Lebedew Institut für Physik der Akademie der Wissenschaften USSR, Moskay, USSR. Vorgelegt von G. Szigeti [Gyorgy Szigeti]

KROCHMAL, Franciszek; HELTOWSKA, Maria

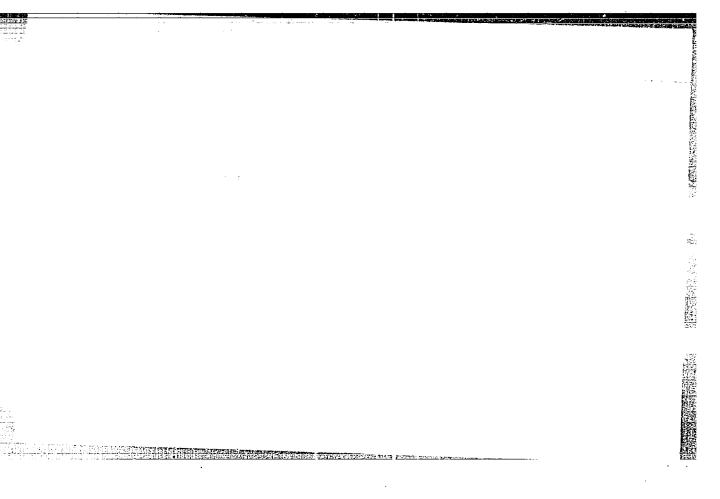
Influence of cations on the behavior of zinc anodes. Mat chemia no. 7:61-69 163.

1. Katedra i Zaklad Chemii Fizycznej, Uniwersytet im. Adama Mickiewicza, Poznan.

KROCHMAL, Franciszek; STENCEL, Marian

Influence of anions on the anodic behavior of metallic zinc.
Mat chemia no.6134-43 '62.

1. Katedra i Zaklad Chemii Fizycznej, Uniwersytet im. Adama Michiewicza, Poznan.



# "APPROVED FOR RELEASE: 06/14/2000 CIA-RDP86-00513R000826620002-5

NAPIORKOWSKI, Jan, mgr inz.; KROCHMAL, Wienlaw, mgr inz.; CIESLAK, Albin, inz.

A case of downfall of the driver's cab with the operating crew from a steel frame traveling bridge. Emergetyka Pol 15 no.10:316-318

# KROCHMAL-KARA, Maria

Floristic notes from Lopuchowko forest near Poznan. Biologia Poznan no.5:115-120 '64.

1. Department of Plant Taxonomy and Geography of the A. Mickiewicz University, Poznan.

# HARMANN, Wiktor; KORN, Helena; KROCHMALSKA, Emilia

Hearing and equilibrium disorders following cranial injuries. Otolaryng. Pol. 16 no.la:237-248 '62.

1. Z Kliniki Laryngologicznej AM w Bialymstoku Kierownik: doc. dr med. W. Hassmann.

(SKULL wds & inj) (DEAFNESS etiol) (EQUILIBRIUM)

# KROCHMAISKA, Emilia

Labyrinthine manifestations of Barre-Lieou cervical syndrome. Pol. tyg.lek. 18 no.47:1761-1764 18 N\*63.

1. Z Kliniki Otolaryngologicznej AM w Bialymstoku; kierowniks prof.dr.med. W. Hassmann.

8/185/61/006/005/016/019 D274/D303

Brodin, M.S., and Krochuk, A.S.

AUTHORS:

Fine structure and temperature dependence of CuCl single crystals absorption-spectrum TITLE:

Ukraying'kyy fizychnyy zhurnal, v. 6, no. 5, 1961, PERIODICAL:

TEXT: Plane-parallel single-crystals, 5 - 40 µ thick, were preparation plane parallel single-crystals, by machanical magnetic magnetic machanical magnetic red; no thinner plate could be obtained by mechanical means. The red; no thinner plate could be obtained by mechanical means. The absorption spectrativere obtained at temperatures of 4.2, 20.4, 150 and 2900k on a spectrograph with a dispersion of 4 Å/mm; the reand 2900k on a spectra were photographed at 20.40k with a dispersion of and 2900k on a spectra were photographed at 20.40k with a dispersion of the absorption edge for a flection spectra were photographed at 20.40k with a dispersion of and 2000k on a spectra were shows the curves of the absorption edge for a flection appearance shows the four indicated values of the 4.20k. The specimen 25 µ thick, at the four indicated values of the specimen 25 µ thick, at the four observed. One at T = 4.20k. re. Two strong absorption-bands were observed, one at T = 4.20K,  $v \approx 25834$  cm-1 and the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the other at m = 20 AOV with a market of the market of the other at m = 20 re. Two strong absorption-bands were observed, one at T = 4.27k,  $v \approx 25834$  cm-1, and the other at T = 20.40k with a reflection maximum at v = 26435 cm-1. These bands are apparently exciton bands. mum at V = 20477 cm -. These cands are apparently exclusion cands. They were also observed in polycrystalline films by R. Reiss and

Card 1/3

APPROVED FOR RELEASE: 06/14/2000

CIA-RDP86-00513R000826620002-5"

S/185/61/006/005/016/019 D274/D303

Fine structure and temperature ...

S. Nikitine (Ref. 3: C.r. Acad. Sci., 250, 2862, 1960), where the presence of weak bands between the above two bands, was observed. The authors were however unable to observe these weak bands. On the other hand, the authors observed two weak and very narrow bands on the longwave side of the band v = 25834 cm<sup>-1</sup>. They are best observed at liquid helium temperature, and are broadened on increase of temperature. These bands have two interesting properties: their relative intensity varies from crystal to crystal, so that in one specimen the first band is stronger and in another specimen - the second; in addition, their intensity depends little on thickness of specimen. Another characteristic feature of the absorption bands of CuCl, is the non-monotonic temperature shift of the absorption edge; the authors concluded that the maximum of the strong absorption band v = 25834 cm<sup>-1</sup> at T = 4.2°K, is also non-monotonically temperature dependent. The narrow bands, 25642 and 25694 cm-1 have a similar temperature shift. The non-monotonic character of the temperature shift is an indication of the complex absorption mechanism and deserves further study. Further, the peculiar features of the narrow bands are related to the inhomogeneity of impurity centers.

Card 2/3

APPROVED FOR RELEASE: 06/14/2000 CIA-RDP86-00513R000826620002-5"

Fine structure and temperature ...

S/185/61/006/005/016 1019 D274/D303

whome field influence the corresponding exciton levels. As the authors did not confuct crystallographic investigations, they were unable to ascertain the relationship between the anisotropic character of the stals and the peculiarities of the narrow bands. There are 2 figures and 6 references: 3 Soviet-bloc and 3 non-Soviet-bloc. The reference to the English-language publication reads as follows: R. Coelho, Techn. Rep. 143, Mass (USA), October 1960.

ASSOCIATION: Instytut fizyky AN URSR m. Kyyiv (Institute of Physics AS UkrsSR, Kyyiv)

SUBMITTED: June 10, 1961

Card 3/3

BRODIN, M.S.; KROCHUK, A.S.

Anomalous dependence of absorption intensity on thickness in CuCl single crystals. Fiz. tver. tela 5 no.12:3609-3611 D '63. (MIRA 17:2)

1. Institut fiziki AN SSSR, Kiyev.

# BRODIN, M.S.; KROCHUK, A.S.

Optical properties of a phenanthrene single crystal in the region of main exciton absorption bands. Ukr.fiz.shur. 7 no.11:1205-1213
N '62. (MIRA 15:12)
(Phenanthrene crystals—Optical properties) (Excitons)
(Dispersion)

45077

24.3150

S/051/63/014/001/014/031 E039/E120

AUTHORS:

Brodin, M.S., and Krochuk, A.S.

TITLE :

Peculiarities of the optical absorption of CuCl single crystals

PERIODICAL: Optika i spektroskopiya, v.14, no.1, 1963, 88-93

TEXT: Samples of CuCl, which belongs to the cubic system and plates (10 μ or more thickness) from large single crystals grown at the Institut Kristallografii AN SSSR (Institute of Crystallography, AS USSR). These crystals were uniform and colourless with a mirror finish on their surfaces. They were of fixing did not influence their spectra. Photographic recording was used on a diffraction grating spectrograph with a dispersion provided a continuous spectrum in the region investigated.

20.4 and 4.2 K. Reflection spectra were obtained using normal Card 1/2

Peculiarities of the optical ..

S/051/63/014/001/014/031 E039/E120

shaped samples were used to avoid light reflected from the back surface entering the spectrograph. At low temperatures strong bands were observed which are ascribed to exciton excitation. The temperature displacement of the edge of the spectrum is not monotonic, hence confirming the complex character of absorption. Near the intensity maximum 25 830 cm<sup>-1</sup> at 4.2 K three narrow weak bands were observed at 25 642, 25 694 and 25 706 cm<sup>-1</sup> which can be grouped in a hydrogen-like series, described by the relation

$$\gg_n = 25 \ 710 - \frac{68}{n^2} \ cm^{-1}$$

where n = 1, 2 and 3. There are 4 figures.

SUBMITTED: December 20, 1961

Card 2/2

BACZKOWSKI, Tadousz, KROCIN, Andrzej

Contraction of chromnickel steel alloy in the light of our cwn experiments. Czas. stomat. 19 no.1:59-62 Ja 1 66

1. Z Kliniki Stomatologicznej AM w Warszawie (Kierowniki prof. dr. J. Galasinska-Landsbergerowa) i z Panstwowej Medycznej Szkoly Technikow Dentystycznych w Warszawie (Kierowniki lek. med. lek. dent. R. Tracz).

Distr: 4E2d(b) 2 cys

New thermocouple for high-temperature measurements.
Ottomar Kröcker (Phys. Lab., VEB Ceramic Works,
Neenhause-Scherschmitz, Czech.), 33/iad 7 zez. 11, 108-11
(1800).—The new-type Modi-Alo couple is stable, even in
the stable of Modis applied by treatment with SiCl, in a H atm. at
1000°. The thermocouple is much superior to Modi-Pt
(Arvin, CA 47, 10935g). The brittle Modis, cannot be
formed into a wire; it is used as a tubular body on which
the Mo wire is weided. The whole element is protected by
a ZrO, ceramic tube, and sintered at 1700-820° in a furnace. Sintered Alo, is not suitable as an insulating material because it forms a low-melting cutectic with the SiO,
in AT P-112 - 12 cm. 17 in the element is C.
aging ceases after some hrs. of service. The couple is
stable up to 1700° in ordicing and 1850° in reducing attra,
and has a lifeting superior to that of Pt-Rh-18 couples.
W. Eird

KROKHA, P.M.; SADKOVSKIY, V.A.; CHENDYLOVA, V.A.; GAL'PERIN, I.S., inzh.

Eliminate the shortcomings in planning. Put' i put. khoz. 9 no.11:32 '65. (MIRA 18:11)

1. Nachal'nik putevoy mashinnoy stantsii No.124, stantsiya Chernovtsy, L'vovskoy dorogi (for Krokha). 2. Glavnyy inzh. putevoy mashinnoy stantsii, stantsiya Chernovtsy, L'vovskoy dorogi (for Sadkovskiy). 3. Glavnyy bukhgalter, stantsiya Chernovtsy, L'vovskoy dorogi (for Chendylova). 4. Stantsiya Chernovtsy, L'vovskoy dorogi (for Gal'perin).

#### KROCZAK J.

KRCCZAK J. Miejskiego Szpit. dla Dzieci w Zabrzu. \*Leczonie gruzliczego zapalemia opon mozgowo-rdzeniowych u dzieci. Treatment of tuberculosis meningitis in children POLSK.TYG.LEK.1953, 8/33 (1137-1145) Graphs 2 Tables 6 and 8/3h (1183-1186) Tables 2

The results of treatment in the years 1948-1950 are reported. 280 children were treated. Of these 117 died; 46 were discharged without any improvement; permanent recovery (they were followed up for 1-2 yr.) was obtained in 65 cases., i.e. in 30%. The worst results were in children under 3 yr. of age and in those who were brought to the hospital in late stages of the disease. The treatment was based on streptomycin administered intramuscularly (20-30 mg./kg.) and intrathecally (1-5 mg./kg.) The patients were also given PAS or nitrogranulogen. In consideration of the frequent failure of the methods of treatment most commonly used, the author emphasizes the necessity of protecting young children against the infection.

Eogdanowicz - Warsaw (XX,7,8,15)

SO: EXCERPTA MEDICA, Section 8, Vol. 7, No.5. May 1954

CHWALIBOGOWSKI, A.; KROCZAK, J.; SPETT, J.; METZGER, M.; BOMANSKA, K.; RUDNICKA, I.; SROCZYESKA, M.

Role of Salmonella and Shigella in etiology of diarrheas in in infants and small children. Pediat. polska 31 no.2:139-154 Feb 56.

1. Z Kliniki Chorob Dzieciecych Sl. A.M. w Zabrzu. Kierownik: prof. dr. med. A. Chwalibogowski i s Zakladu Mikrobiologii Sl. A.M. w Zabrsu Kierownik: prof. dr. med. S. Slopek. Zabrse, ul. 3 Maja 63, Klinika Chorob Dzieci A.M.

(SALMONELIA INFECTIONS, in infant and child, diarrhea (Pol))

(SHIGELIA, infections,

diarrhea in inf. & child. (Pol))

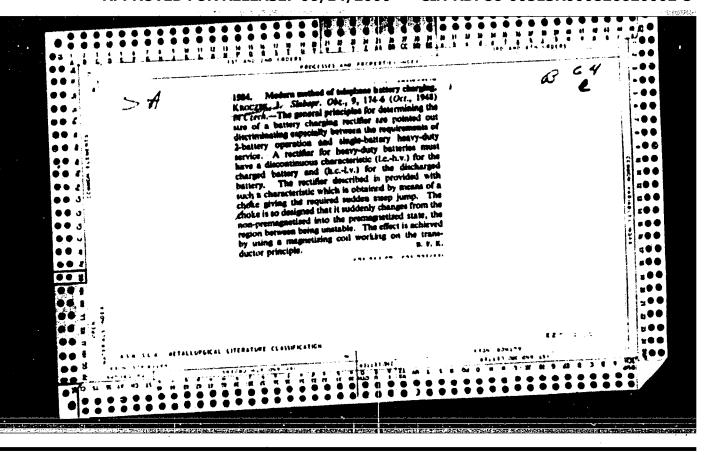
(DIARRHEA, in infant and child,

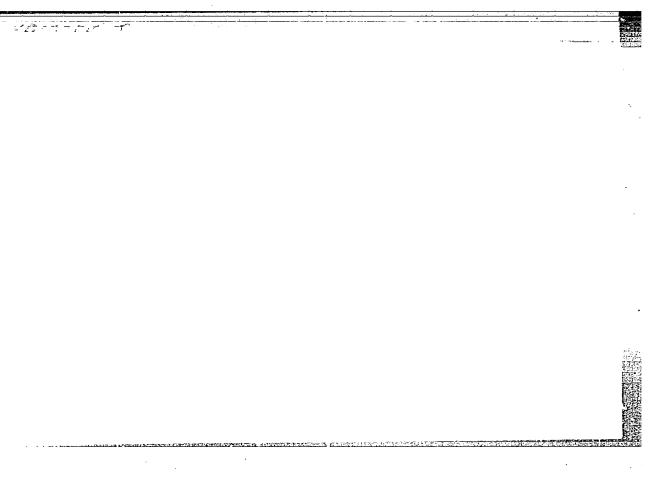
Salmonella & Shigella Infect. (Pol))

APPROVED FOR RELEASE: 06/14/2000

CIA-RDP86-00513R000826620002-5"

# "APPROVED FOR RELEASE: 06/14/2000 CIA-RDP86-00513R000826620002-5





KROCZEK, J., inz., dr.; VIKOPAL, K.; HRUBY, V.

Selenium rectifiers in power industries. Energetika Cz
7 no.2177-81 F 157.

### KROCZEK, J.

"The transistor as a controlling, connecting, and switching element in power-current engineering."

Elektrotechnicky Obzor. Praha, Czechoslovakia. Vol. 47, no. 10, Cct. 1958.

Monthly list of East European Accessions (EEAI), IC, Vol. 8, No. 6, Jun 59, Unclas

KROCZEK, J.

TECHNOLOGY

ELEKTROTECHNICKY. OBZOR.

KROCZEK, J. New semiconductor rectifying systems. p. 613.

Vol. 117, no. 12, Dec. 1958.

Monthly List of East European Accessions (SEAI), 10, Vol. 8, no. 5 May 1959, Unclass.

KROCZEK, J.: SLAVIN, J.: RODES, J.

TECHNOLOGY

PERIODICAL: ADTA TECHNICA VOL. 4, no 2, 1959

KODES, J.: KROCZEK, J.: SLAVIK, J. Optical control of charges in selenium rectifiers. In German, p. 132

Monthly List of East European Accessions (EEAI), LC, Vol. 8, no. 5
May 1959, Unclass.

# "APPROVED FOR RELEASE: 06/14/2000 CIA-RDP86-00513R000826620002-5

KROCZEK.

"Technology of monocrystals."

Elektrotechnicky Obzor. Praha, Czechoslovakia. Vol. 48, no. 2, Feb. 1959.

Monthly list of East European Accessions (EEAI), LC, Vol. 8, No. 6, Jun 59, Unclas

### KROCZEK, J.

How selenium rectifiers can compete with germanium and silicon rectifiers. p. 507.

ELEKTROTECHNICKY OBZOR. (Ministerstvo tezkeho strojirenstvi a Ceskoslovenske vedecka technicka spolecnost pro elektrotechniku pri Ceskoslovenske akademii ved)
Praha, Czechoslovakia, Vol. 48, No. 10, Oct. 1959.

Monthly List of East European Accession, (EEAI), LC, Vol. 8, No. 12, Dec. 1959, Uncl.

KROCZEK, J.

83992 2/017/60/049/010/001/002 E192/E482

9,4360

AUTHOR:

Ageing of Selenium Rectifiers with an Artificial Barrier Kroczek Julius, Inz. dr. RNDr.

TITLE

Card 1/4

PERIODICAL: Elektrotechnický obzor, 1960, Vol.49, No.10, pp 516-520 The inverse breakdown or operating voltage of a selenium rectifier can be increased by depositing an artificial barrier rectifier can be increased by depositing an artificial barrier on to a selenium plate.

layer on to a selenium plate.

produced by sulphurizing, but recently a new technology was introduced; but recently a produced by surpnurizing, but recently a new technology was introduced the inverse voltage of selenium elements is increased by dipping the elements in an alcohol or acatoms solution of notogetum manganate. elements in an alcohol or acetone solution of potassium manganate. elements in an alcohol or acetone solution of potassium manganate.

In the following an attempt is made to explain the influence of such processing on the life of a selenium rectifying element. assumed that during the passage of current through a sclenium element, electric charges are produced by the perturbation regions The conductivity of the element It is known that the conductivity is dependent on the concentration of impurities and is approximately situated in the selenium layer. is a property of its structure. structure remains unchanged, the conductivity is constant. proportionate to it.

APPROVED FOR RELEASE: 06/14/2000

CIA-RDP86-00513R000826620002-5

83992

Z/017/60/049/010/001/002 E192/E482

Ageing of Selenium Rectifiers with an Artificial Barrier Layer other hand, a change in conductivity is due to a change in structure. Consequently, the changes in conductivity are due to the changes in the concentration of active perturbation regions. This change in the concentration in a selenium layer is due to diffusion. The changes caused by continuous operation of a selenium element are therefore due to diffusion phenomena. The diffusion effect is described by

 $\frac{\partial c}{\partial t} = p \left( \frac{\partial^2 c}{\partial x^2} + \frac{\partial^2 c}{\partial y^2} + \frac{\partial^2 c}{\partial z^2} \right)$  (1)

where c is the concentration and D is the diffusion coefficient. If the diffusion is unidimensional in the direction of  $x_1$  Eq.(1) can be written as

$$\frac{\partial f(x,t)}{\partial t} = D \frac{\partial^2 f(x,t)}{\partial x^2}$$
 (2)

where f  $(\mathbf{x},\mathbf{t})$  is the distribution function for the particles Card 2/4

83992

Z/017/60/C49/010/001/002 E192/E482

Ageing of Selenium Rectifiers with an Artificial Barrier Layer The solution of Eq.(2) is in the form in space and time.

$$f(x,t) = \frac{N}{2\sqrt{\pi Dt}} e^{-\frac{x^2}{4Dt}}$$
 (3)

The total number of the diffused particles can therefore be expressed by Eq.(5). By introducing a new variable, Eq.(5) can be written as Eq. (5a), which is in the form of the Gaussian integral. The above formulas can be used to study the ageing of selenium Fig. 2 shows the dependence of the differential resistance  $\beta$  of an element on the thickness of an artificial barrier layer. If the curve in Fig. 2 is shifted downwards, which corresponds to a reduction in  $\beta$ , a new curve  $\beta$ ' is obtained. From this it is possible to determine the thickness of the insulation layer which increases due to the diffusion of potassium On the other hand, if the static current-voltage characteristics of a selenium element are known when the element was new and after it was shelf-stored for a long period of time, Card 3/4

83992

Z/017/60/049/010/001/002 E192/E482

Ageing of Selenium Rectifiers with an Artificial Barrier Layer it is possible to determine the thickness of the inverse conducting layer by determining the change in  $\beta'$ . Fig. 6 shows the characteristics of a 40 x 40 mm<sup>2</sup> selenium element. The initial characteristics (Curve a) and the characteristic after half-year storage, indicate that  $\beta'$  increased from 71.2 to  $79\Omega/cm^2$ . The barrier layer thus increased from 8.5  $\mu$ m to  $9 \mu$ m. From this it can be found that the diffusion coefficient is  $D = 2 \times 10^{-18} \, cm^2/s$ . By using this diffusion coefficient, it is possible to determine further ageing of the selenium element. There are 9 references:

ASSOCIATION: CSAV (Czechoslovak Academy of Sciences)
SUBMITTED: May 4, 1960

Card 4/4

Z/017/60/C49/011/010/013 E073/E535

AUTHOR:

Kroczek, Julius, Engineer Doctor, Doctor of Natural

Soiences

Alberty & Miller

Physical-Technical Analysis of Single Crystal TITLE:

Semiconductor Rectifiers 25

PERIODICAL: Elektrotechnický obzor, 1960, Vol.49, No.11, pp. 588-596

The aim of the paper is to give general information to readers who are not acquainted with the physical and technical fundamentals of single crystal semiconductor rectifiers. The problem is introduced by a typical description of the p-n junction. This is followed by an analysis of the electric forces in the microstructure of matter and their dependence on the properties of the material from the point of view of the periodic system. The polar nature of electrical conductivity of pure and contaminated single crystals is explained and dissociation and recombination up to the quantitative determination of the current are analysed. extension to band models of semiconductors using the Fermi-Dirac function and the Fermi level, is applied for elucidating the

Card 1/2

Z/017/60/049/011/010/013 E073/E535

Physical-Technical Analysis of Single Crystal Semiconductor Rectifiers

phenomena involved. There are 13 figures, 1 table and 9 references: 5 Czech and 4 German.

ASSOCIATION: ČSAV

SUBMITTED: July 20, 1960

Card 2/2

SANDEROVA, Vera, Prom. Phys., Asistent; KROCZEK, Julius, Dr. Ing.RNDr; SLAVIK, Josef B., Ing.RNDr, Prof.

Reversible and irreversible changes of structure and conductance during the heat treatment of selenium. Acta techn Cz 6 no.2:117-123 '61. (EEAI 10:6)

1. Direktor des Physik Instituts der Technischen Hochschule, Praha (for Slavik). 2. Institut der Technischen Hochschule, Praha (for Sanderova). 3. Tschechoslowakische Akademie der Wissenschaften, Institut für Elektrotechnik (for Kroczek) (Selenium)

KROCZEK, Julius, Dr. Ing., RNDr.

Problem of aging of selenium rectifier discs with an artificial barrier level. Acta techn Cz 6 no.5:474-483 161.

1. Ceskoslovenska akademie ved, Ustav pro elektrotechniku, Praha 1, Vaclavske namesti 55.

(Electric current rectifiers)

CIA-RDP86-00513R000826620002-5" APPROVED FOR RELEASE: 06/14/2000

z/039/62/023/007/001/005 р409/р301

9.2150 AUTHORS: Kronzek, Julius, Doctor, Engineer, and Slavik, Josef B., Professor, Doctor of Sciences, Engineer

Aging of semiconductor, namely selenium rectifiers

TITLE:

Slaboproudy obzor, v. 23, no. 7, 1962, 369 - 373

Since the service life of selenium rectifiers is considerably shortened by aging, the causes of this phenomenon are PERIODICAL: investigated with the aid of characteristics changes and provisions listed which limit the aging effect and make selenium rectifiers a TEXT: dependable electrical component. The physical reason for aging, resulting in an increased resistance in a forward direction, is a structural change in the selenium layer, caused by a diffusion process and accelerated by elevated operating temperatures. In this process, activators diffuse from the selenium layer and deactivators (atmospheric oxygen and chemically active elements used in Silicon disc manufacture) diffuse into the selenium layer. Classical diffusion laws can therefore

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Z/039/62/023/007/001/005 D409/D301

Aging of semiconductor, ...

be used also for quantitative determination of the semiconductor aging process. To limit the aging effect at least in a forward direction, the following technology for selenium-disc preparation is recommended: To increase the stability of the selenium layer, special attention must be paid to the transformation from one into another crystal modification. For both pressed-on and vapor-coated selenium layers, the transformation should be carried out at 140 - 218 °C and the completion of the recrystallization process should be checked by direct electrical conductivity measuring or by a photometer using surface reflection. Only such raw materials should be used which have a low diffusion coefficient and low chemical affinity to the activator, or intermediate layers should be applied to prevent detrimental effects on activators. Oxidation should be avoided during production as much as possible, and discs of air-cooled rectifiers should be protected by laquer coatings. There are 3 figures.

ASSOCIATION: Ústav pro elektrotechniku ČSAV, Praha (Electrical Engineering Institute, Czechoslovak AS, Prague) (J. Kroczek);
Fyzikální ústav elektrotechnické fakulty ČVUT, Praha

Card 2/3

Aging of semiconductor, ... Z/039/62/023/007/001/005
D409/D301

(Physical Institute of the Electrical Engineering (J.B. Slavik)

SUBMITTED: March 15, 1962

Card 3/3

3**272**9 Z/017/62/051/002/001/004 D291/D301

9,2150 (1020,1159,133)

Kroczek, Julius, Engineer, Doctor of Natural Sciences,

and Kodes, Jiri, Engineer

TITLE:

AUTHORS:

Aging of silicon rectifiers

PERIODICAL: Elektrotechnický obzor, v. 51, no. 2, 1962, 64-67

TEXT: The article points out the importance of the stability of the silicon p-n junction and deals with tests which were conducted to prevent a drop in the blocking effect, resulting in a gradual shift of the blocking characteristic and endangering the p-n junction. Silicon diodes with medium quality parameters were loaded in a thermostat at an ambient temperature of 100°C by a d.c. blocking voltage of 100 V. The blocking characteristics were impaired during a period of 40°C hrs, whereupon they again improved. The throughflow loss invariably remained 1.3 V. The aging was assumed to have been caused by a mutual diffusion of the elements in the p-n junction or those elements surrounding it. These tests have shown that silicon diodes are not ideally stable, however,

Card 1/2

32729 Z/017/62/051/002/001/004 D291/D301

Aging of silicon rectifiers

and that the barrier diffusion in the p-n junction is very small without having any appreciable adverse effect upon their operation and economic suitability. The author points out that the residual gases and vapors between the envelope and the surface of the wafer at first cause an increase in the blocking currents, however, that these blocking currents later stabilize. In conclusion it is recommended that before leaving production for operational use, semiconductor dices should be artificially aged by being subjected to high temperatures which would not only reveal hidden defects that also stabilize the technical parameters. The author thanks Professor, Engineer, Doctor J. Slavik for making available the facilities of the Physical Institute of the CVUT, and to Engineer M. Kubát. There are 1 figure and 1 Soviet-bloc reference.

ASSOCIATION: ČVUT (Kodeš); ČSAV (Kroczek)

SUBMITTED: November 9, 1961

Card 2/2

2/017/62/051/007/001/002 D409/0301

Kroczek, Julius, Engineer, Doctor of Natural

AUTHOR:

Controlled semiconducting elements including inter-metallic allows and their application in heave-curvontrolled semiconducting elements including inter-metallic alloys and their application in heavy-cur-Sciences

TITLE:

Elektrotechnický obzor, v. 51., no. 7, 1962, 313-319

This article, predominantly based on Western sources, predominantly based on Western sources, predominantly based on Western sources, examines the applicability of semiconducting elements for heavy-curexamines the applicability of semiconducting elements four-layer examines the applicability of detail the function of the four-layer rent control. describes in detail the examines the applicability or semiconducting elements for neavy-control of the four-layer rent control, describes in detail the function of the field transistor, and lists the development of techniques. rent control, describes in detail the function of the four-layer field transis- field transis- frequency field transis- frequency field transis- frequency for transistor, and lists the development of termetallic compounds for transistor, and semiconducting frequency PERIODICAL: que to les nigh losses, other translstor types have been developed is the four-layer diode for this special purpose. Most widely used is the four-layer diode

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**VED FOR RELEASE: 06/14/2000** 

CIA-RDP86-00513R000826620002-

Controlled semiconducting ...

Z/017/62/051/007/001/002 D409/D301.

(trinistor) which actually is a controlled rectifier or 'silicon' thyratron, only that it is more efficient, reliable, and smaller than the gas-tube thyratron or the controlled mercury rectifier. Trinistors which operate in a temperature range of -50 to +50°C, are successfully used to replace controlled mercury rectifiers up to 400 V d-c, and mercury thyratrons in d-c control. However, special circuits also permit the use of trinistors to regulate d-c sources, eventually for d-c to a-c conversion. Efforts to eliminate the disadvantages of thyratron control systems led to the development of the tecnetron, the field transistor, and intermetallic compounds where the conductivity of the semiconducting element is controlled by an electric or magnetic field respectively. Nost suitable for magnetic conductivity control (Hall effect) are intermetallic compounds with great movability of charge carriers, namely InSb and InAs. These semiconducting intermetallic compounds can be used for continuous d-c regulation, d-c to a-c conversion, etc; however, they require a special purification and recrystallization technology. There are 10 figures. The most recent English language reference is: F. Herman, M. Glicksman, R.H. Parmenter: Semiconductor Alloys. Pro-Card 2/3

### "APPROVED FOR RELEASE: 06/14/2000 CIA-RDP86-00513R000826620002-5

Controlled semiconducting ...

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SUDMITTED:

March 12, 1962

Card 3/3

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KODES, Jiri, inz.; KROCZEK, Julius, inz., dr., RNDr.; SIAVIK, Josef B., inz., prof., RNDr.

Diffusion effects in selenium rectifiers demonstrated orga thallium-selenium boundary layer. Acta techn Cz 8 no.2:112-119 '63.

1. Assistent am Physikalischen Institut, Technische Hochschule, Praha 2, Karlovo namesti 13 (for Kodes). 2. Tschechoslowakische Akademie der Wissenschaften, Praha 1, Vaclavske namesti 55 (for Kroczek). 3. Direktor des Physikalischen Institutes, Technische Hochschule, Praha 2, Karlovo namesti 13 (for Slavik).

# KROCZEK, De.

Seminar on measurement and classification of semiconductor valves in Prague, September, 1962. El tech obsor 52 no.1:55 Ja '63.

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Silicon controlled rectifiers in servoengineering. El tech obsor 52 no.5:255-256 My '63.

KROCZEK, Julius, inz. dr., RNDr.; KUHNERT, Max, Dipl. inz.; MOLNAR, Istvan, Dipl. inz.; WDOWIAK, Janusz, Mgr. inz.

Measurement of some important control quantities of power semiconductor valves. El tech obsor 52 no.7:361-364 Jl 163.

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SANDEROVA, Vera, promovany fyzik; KROCZEK, Julius, inz.dr., RNDr. BOCH, Karel.

Effect of different concentrations of bromine activator on the first heat change in selenium layers of selenium rectifiers. Kl tech obzor 52 no.ll: 584-587 N\*63.

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POLAND / Soil Science. Minoral Fortilizors.

J-4

Abs Jour

: Rof. Zhur - Biologiya, No 17, 1958, No. 77437

Author

: Kurylowicz, Bolosław; Gasiorowski, Stanisław; Kroczynski,

Josof

Inst

: Agrochomistry Instituto

Titlo

: Rosults of Invostigations Evaluating Magnosium Thormophos-

phato

Orig Pub

: Postopy nauk. roln., 1957, 4, No 1, 45-57

Abstract

: The Department of Sulfuric Acid and Phospherus Fortilizers of the Agreehomistry Institute investigated in vegetative and field tests the effectiveness of magnesium thermophosphate obtained by the fusion of 25 parts of apatite, 75 parts of local phospherites and 70 parts of serpentine at 1350-1500°. The thermophosphate centained 14% of common P205 and 11.8% of a citrate-soluble, SiO2 - 34.1%,

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APPROVED FOR RELEASE: 06/14/2000 CIA-RDP86-00513R000826620002-POLAND / Soil Science. Mineral Fertilizers.

Abs Jour : Rof. Zhur - Biologiya, No 17, 1958, No. 77437

R203 - 9.4%, CaO - 31.5%, MgO - 9.1%, F - 0.2%. The fineness of the grist is considered sufficient when 80% of the material passes through a slove having a 1600 per cm² mosh. In the summary, the Department also included tests of the nutrition of plants and fortilizer of the Secondary Agricultural School in Warsaw and tests conducted in Czechoslevakia. On soils of acid and poor P205, thermophesphate offected a better Pc, which is predeminately on the more cultivated soils. -- Z. I. Zhurbitskiy.

SUREWICZ, Wlodzimierz, doc. dr; DABROWSKI, Jozef, mgr inz. KROCZYNSKI, Slavomir, mgr inz.

Bleaching of semichemical neutral natrium sulfit: rulp masses obtained from birchwood. Przegl papier 20 no.12: 385-392 D 164.

1. Department of Pulp and Paper Technology of the Technical University, Leds.